

NPN Triple Diffused Planar Silicon Transistor

Absolute Maximum Ratings I _c =25°C unless otherwise noted					
Symbol	Parameter	Rating	Units		
V _{CBO}	Collector-Base Voltage	1500	V		
V _{CEO}	Collector-Emitter Voltage	750	V		
V _{EBO}	Emitter-Base Voltage	6	V		
Ι _C	Collector Current (DC)	10	Α		
I _{CP} *	Collector Current (Pulse)	20	А		
P _C	Collector Dissipation	60	W		
T	Junction Temperature	150	°C		

Absolute Maximum Ratings T. -25°C unless otherwise noted

T_{STG} Storage Temperature * Pulse Test: Pulse Width=5ms, Duty Cycle <u><</u> 10% Storage Temperature

Electrical Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
I _{CES}	Collector Cut-off Current	V _{CB} =1400V, R _{BE} =0			1	mA
I _{CBO}	Collector Cut-off Current	V _{CB} =800V, I _E =0			10	μA
I _{EBO}	Emitter Cut-off Current	V _{EB} =4V, I _C =0			1	mA
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =500μA, I _C =0	6			V
h _{FE1} h _{FE2}	DC Current Gain	V _{CE} =5V, I _C =1A V _{CE} =5V, I _C =6A	10 5		8	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =6A, I _B =1.5A			3	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =6A, I _B =1.5A			1.5	V
t _{STG} *	Storage Time	V_{CC} =200V, I_{C} =6A, R_{L} =33 Ω			3	μs
t _F *	Fall Time	I _{B1} =1.2A, I _{B2} = - 2.4A			0.2	μs

* Pulse Test: PW=20µs, duty Cycle=1% Pulsed

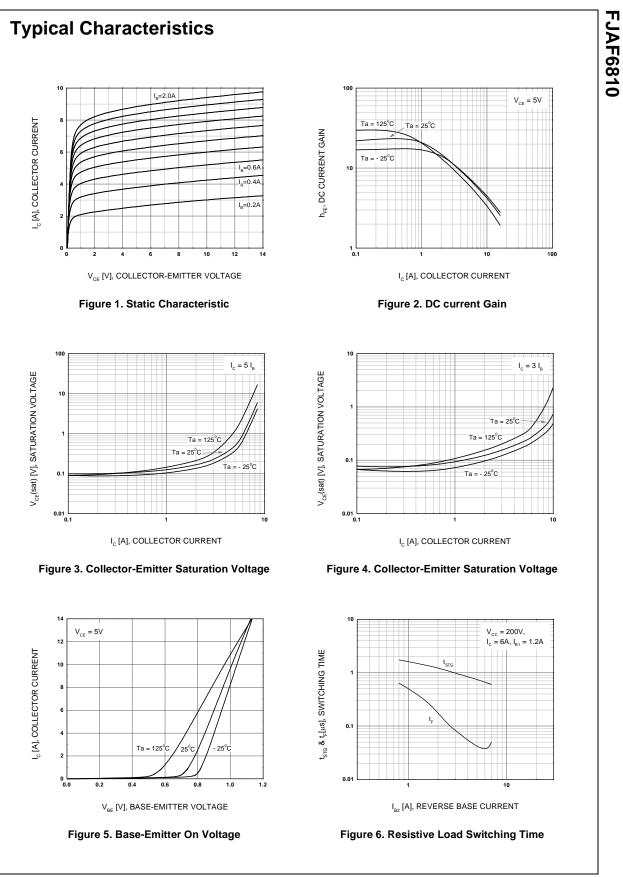
Thermal Characteristics T_C=25°C unless otherwise noted

Symbol	Parameter	Тур	Max	Units
R _{θjC}	Thermal Resistance, Junction to Case		2.08	°C/W

°C

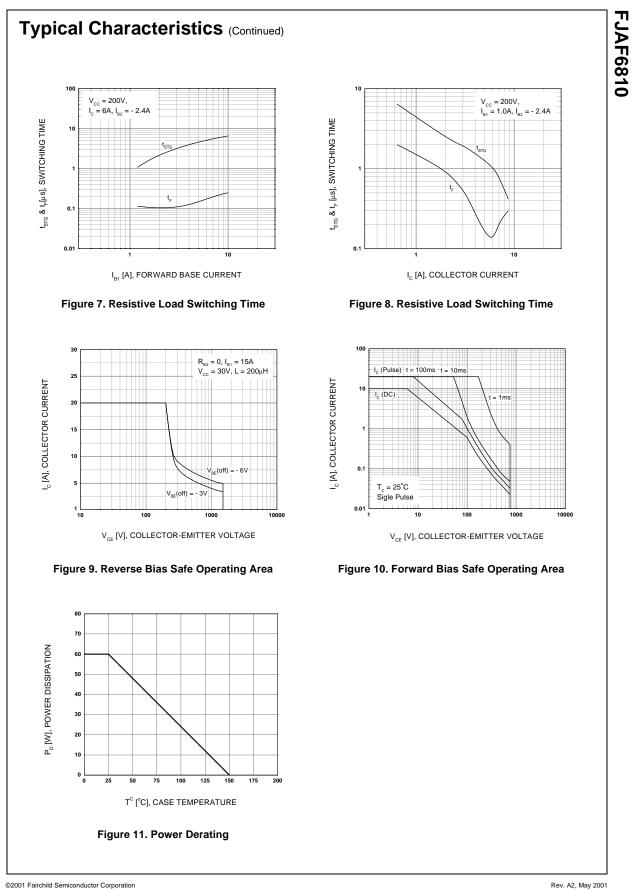
-55 ~ 150

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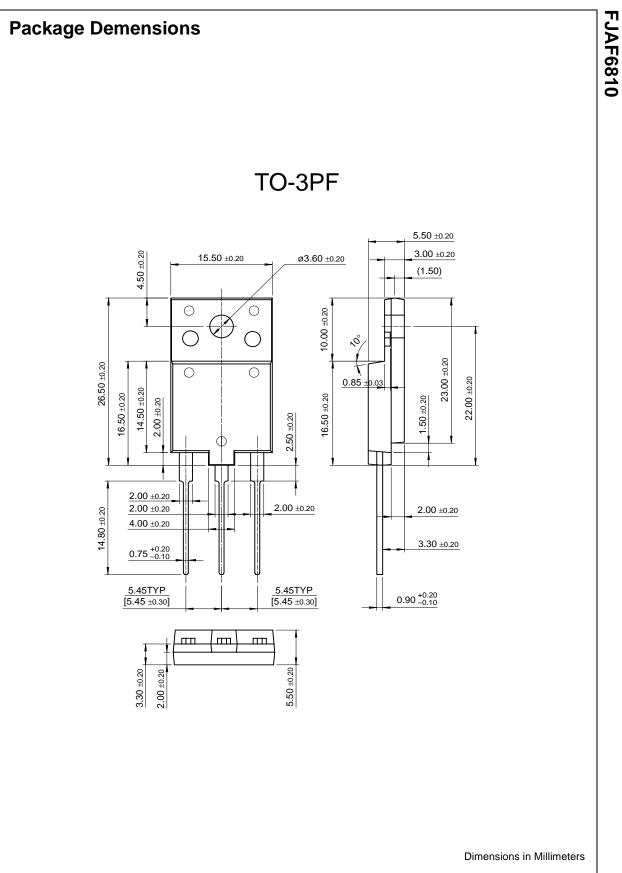
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